NSN 5962-01-480-6506

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Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
C141 awcfs gp
Features Provided:
Ultraviolet erasable and monolithic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
22 input
Product Name:
Microcircuits, digital, memory, cmos, uv erasable-programming, logic array
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
10.00 nanoseconds access
Memory Device Type:
Pal
Special Features:
This item shall be made from an unprogrammed device that is in accordance with smd specifications 5962-8753906lx
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0